# UNR32A3

### Silicon NPN epitaxial planar transistor

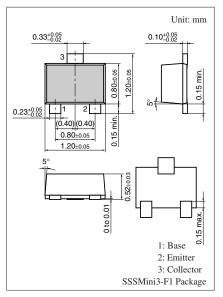
For digital circuits

#### Features

- Suitable for high density package and downsizing of the equipment
- Contribute to low power consumption

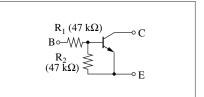
Parameter		Symbol	Rating	Unit					
Rating	Collector to base voltage	V <sub>CBO</sub>	50	V					
of	Collector to emitter voltage	V <sub>CEO</sub>	50	V					
element	Collector current	I <sub>C</sub>	80	mA					
Overall	Total power dissipation	P <sub>T</sub>	100	mW					
	Junction temperature	Tj	125	°C					
	Storage temperature	T <sub>stg</sub>	-55 to +125	°C					

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$



Marking Symbol: FN

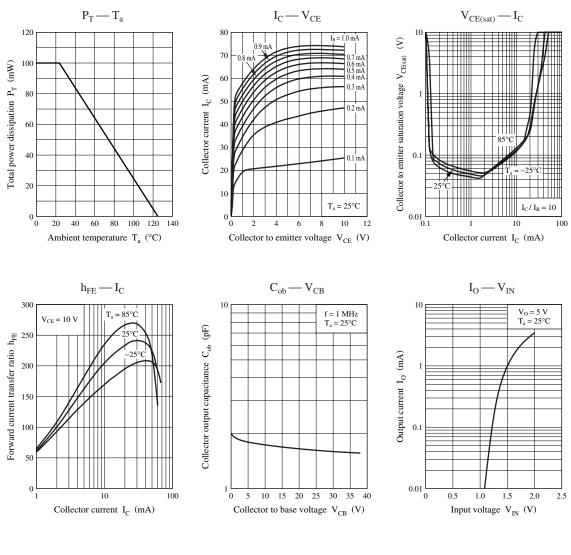
#### Internal Connection

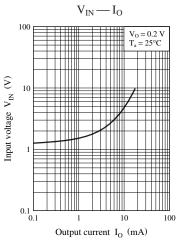


Parameter	Symbol	Conditions	Min	Тур	Мах	Unit
Collector to base voltage	V <sub>CBO</sub>	$I_{\rm C} = 10 \ \mu A, \ I_{\rm E} = 0$	50			V
Collector to emittter voltage	V <sub>CEO</sub>	$I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$	50			V
Collector cutoff current	I <sub>CBO</sub>	$V_{CB} = 50 \text{ V}, I_E = 0$			0.1	μΑ
	I <sub>CEO</sub>	$V_{CE} = 50 \text{ V}, I_B = 0$			0.5	
Emitter cutoff current	I <sub>EBO</sub>	$V_{EB} = 6 V, I_C = 0$			0.1	mA
Forward current transfer ratio	$h_{FE}$	$V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}$	80			—
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0.3 \text{ mA}$			0.25	V
High level output voltage	V <sub>OH</sub>	$V_{CC} = 5 \text{ V},  V_{B} = 0.5 \text{ V},  R_{L} = 1  k\Omega$	4.9			V
Low level output voltage	V <sub>OL</sub>	$V_{CC} = 5 \text{ V},  V_{B} = 3.5 \text{ V},  R_{L} = 1  k\Omega$			0.2	V
Input resistance	R <sub>1</sub>		-30%	47	+30%	kΩ
Resistance ratio	R <sub>1</sub> / R <sub>2</sub>		0.8	1.0	1.2	_
Gain bandwidth product	f <sub>T</sub>	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$		150		MHz

#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

## Panasonic





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